



#### 3.0A SURFACE MOUNT SUPER-FAST RECTIFIER

#### **Features**

- Glass Passivated Die Construction
- Super-Fast Recovery Time For High Efficiency
- Surge Overload Rating to 100A Peak
- Ideally Suited for Automated Assembly
- Lead Free Finish/RoHS Compliant (Note 1)
- Green Molding Compound (No Halogen and Antimony) (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

## **Mechanical Data**

- Case: SMB/SMC
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208 (23)
- Polarity: Cathode Band or Cathode Notch
- SMB Weight: 0.093 grams (approximate)
- SMC Weight: 0.21 grams (approximate)





Top View

Bottom View

#### **Ordering Information (Note 3)**

| Part Number | Case | Packaging        |
|-------------|------|------------------|
| ES3x-13-F   | SMC  | 3000/Tape & Reel |
| ES3xB-13-F  | SMB  | 3000/Tape & Reel |

<sup>\*</sup> x = Device type, e.g. ES3A-13-F (SMC package); ES3AB-13-F (SMB package).

Notes:

- 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied, see EU Directive 2002/95/EC Annex Notes.
- 2. Product manufactured with Data Code 0924 (week 24, 2009) and newer are built with Green Molding Compound.
- 3. For packaging details, go to our website at http://www.diodes.com.

# **Marking Information**



ES3x = Product type marking code, ex: ES3A (SMC package)
ES3xB = Product type marking code, ex: ES3AB (SMB package)

>!! = Manufacturers' code marking

YWW = Date code marking

Y = Last digit of year (ex: 2 for 2002)

WW = Week code (01 to 53)



## Maximum Ratings @TA = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

| Characteristic  | Symbol                                       | ES3A/AB | ES3B/BB | ES3C/CB | ES3D/DB | Unit |
|---|--|---------|---------|---------|---------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage (Note 4)     | $egin{array}{c} V_{RRM} \ V_{R} \end{array}$ | 50      | 100     | 150     | 200     | V    |
| RMS Reverse Voltage   | V <sub>R(RMS)</sub>                          | 35      | 70      | 105     | 140     | V    |
| Average Rectified Output Current @ T <sub>T</sub> = 100°C   | Ю  |         | 3       | .0      |         | Α    |
| Non-Repetitive Peak Forward Surge Current 8.3ms<br>Single Half Sine-Wave Superimposed on Rated Load | I <sub>FSM</sub>                             |         | 10      | 00      |         | А    |

#### **Thermal Characteristics**

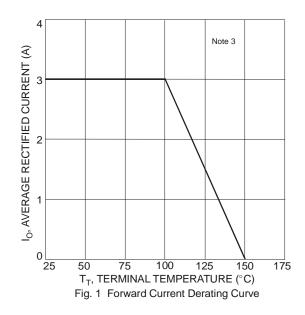
| Characteristic   | Symbol                           | Value       | Unit |
|--|----------------------------------|-------------|------|
| Typical Thermal Resistance, Junction to Terminal         | $R_{	heta JT}$                   | 10          | °C/W |
| Typical Thermal Resistance, Junction to Ambient (Note 5) | $R_{\theta JA}$                  | 50          | °C   |
| Operating and Storage Temperature Range                  | T <sub>J,</sub> T <sub>STG</sub> | -55 to +150 | °C   |

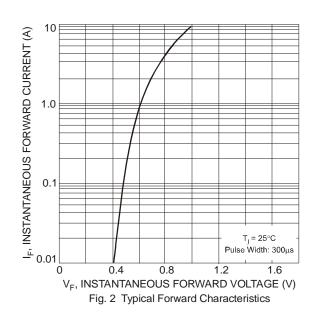
## **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

| Characteristic  |   | Symbol          | Value     | Unit |
|---|---|-----------------|-----------|------|
| Maximum Forward Voltage                                       | $@ I_F = 3.0A$                                      | $V_{FM}$        | 0.9       | V    |
| Peak Reverse Current<br>at Rated DC Blocking Voltage (Note 4) | @ T <sub>A</sub> = 25°C<br>@ T <sub>A</sub> = 125°C | I <sub>RM</sub> | 10<br>500 | μА   |
| Maximum Reverse Recovery Time (Note 6)                        |   | t <sub>rr</sub> | 25        | ns   |
| Typical Total Capacitance (Note 7)                            |   | Ст              | 45        | pF   |

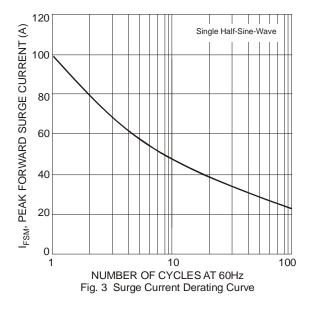
Notes:

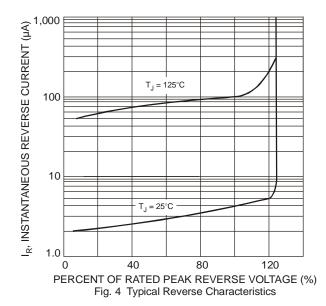
- 4. Short duration pulse test used to minimize self-heating effect.
- 5. Unit mounted on PC board with 5.0 mm² (0.013 mm thick) copper pads as heat sink. 6. Measured with  $I_F = 0.5A$ ,  $I_R = 1.0A$ ,  $I_{rr} = 0.25A$ . See Figure 5. 7. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

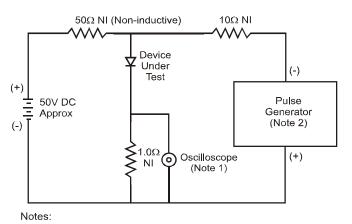


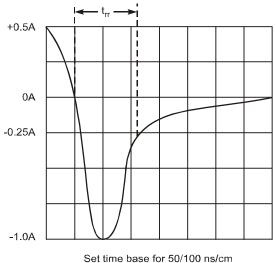








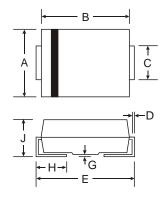




- 1. Rise Time = 7.0ns max. Input Impedance = 1.0M $\Omega$ , 22pF.
- 2. Rise Time = 10ns max. Input Impedance =  $50\Omega$ .

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

## **Package Outline Dimensions**

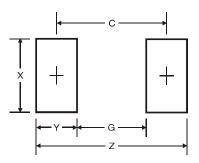


| SMB                  |      |      |  |  |
|----------------------|------|------|--|--|
| Dim                  | Min  | Max  |  |  |
| Α                    | 3.30 | 3.94 |  |  |
| В                    | 4.06 | 4.57 |  |  |
| С                    | 1.96 | 2.21 |  |  |
| D                    | 0.15 | 0.31 |  |  |
| Е                    | 5.00 | 5.59 |  |  |
| G                    | 0.05 | 0.20 |  |  |
| Н                    | 0.76 | 1.52 |  |  |
| J                    | 2.00 | 2.50 |  |  |
| All Dimensions in mm |      |      |  |  |

| SMC                  |                    |      |  |  |
|----------------------|--------------------|------|--|--|
| Dim                  | Min                | Max  |  |  |
| Α                    | 5.59               | 6.22 |  |  |
| В                    | 6.60               | 7.11 |  |  |
| <b>C</b> 2.75 3.18   |                    |      |  |  |
| D                    | 0.15               | 0.31 |  |  |
| <b>E</b> 7.75 8.13   |                    | 8.13 |  |  |
| G                    | <b>G</b> 0.10 0.20 |      |  |  |
| Н                    | <b>H</b> 0.76 1.52 |      |  |  |
| J                    | 2.00               | 2.50 |  |  |
| All Dimensions in mm |                    |      |  |  |



## **Suggested Pad Layout**



| SMB<br>Dimensions | Value (in mm) |  |
|-------------------|---------------|--|
| Z                 | 6.7           |  |
| G                 | 1.8           |  |
| X                 | 2.3           |  |
| Y                 | 2.5           |  |
| С                 | 4.3           |  |

| SMC<br>Dimensions | Value (in mm) |
|-------------------|---------------|
| Z                 | 9.3           |
| G                 | 4.4           |
| Х                 | 3.3           |
| Y                 | 2.5           |
| С                 | 6.8           |

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